

3c971 U.S. PTO
10/028643

12/20/01

U.S. UTILITY Patent Application

PATENT NUMBER and
ISSUE DATE

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10028643	12/20/2001	438	216	2812	L. PHAM

**APPLICANTS: Ahn Kie; Forbes Leonard;

**CONTINUING DATA VERIFIED:

** FOREIGN APPLICATIONS VERIFIED:

PG-PUB DO NOT PUBLISH ☐

RESCIND ☐

Foreign priority claimed ☐ yes ☐ no

35 USC 119 conditions met ☐ yes ☐ no

Verified and Acknowledged Examiner's initials

ATTORNEY DOCKET NO

1303.030US1

TITLE : Low-temperature grown high quality ultra-thin CoTiO3 gate dielectrics

U.S. DEPT. OF COMM./PAT. & TM.-PTO-436L (Rev. 12-94)

NOTICE OF ALLOWANCE MAILED

CLAIMS ALLOWED